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Listing of Claims:

Claim 1 (previously presented) A wafer carrier for carrying a wafer, comprising:

- a transparent base;
- a conducting layer positioned on a bottom surface of the transparent base; and
- a bonding layer positioned on a top surface of the wafer carrier for bonding the wafer and the transparent base together;
- wherein the wafer carrier is attracted by an electrostatic chuck via the conducting layer.
- 10 Claim 2 (original) The wafer carrier of claim 1, wherein the transparent base has dimensions similar to that of the wafer.
 - Claim 3 (original) The wafer carrier of claim 1, wherein the transparent base is a glass wafer.

Claim 4 (original) The wafer carrier of claim 1, wherein the transparent base is a quartz wafer.

Claim 5 (cancelled)

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- Claim 6 (previously presented) The wafer carrier of claim 1, wherein the bonding layer is selected from the group consisting of double-sided tape, ultra violet tape, thermal sensitive tape, photo resist, and wax.
- 25 Claim 7 (previously presented) The wafer carrier of claim 1, wherein the wafer is transferred and undergoes at least a semiconductor process.
 - Claim 8 (original) The wafer carrier of claim 7, wherein the semiconductor process is a double-sided process, and the wafer comprises at least an alignment mark.
 - Claim 9 (original) The wafer carrier of claim 8, wherein the conducting layer is a transparent conducting layer.

Claim 10 (original) The wafer carrier of claim 8, wherein the conducting layer is a non-transparent conducting layer having at least an exposed region corresponding to the alignment mark.

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Claim 11 (original) The wafer carrier of claim 10, wherein the non-transparent conducting layer comprises a plurality of conducting patterns connected with each other.

- 10 Claim 12 (previously presented) A wafer carrier adapted for use in a double-sided process for carrying a wafer, comprising:
 - a transparent base;
 - a conducting layer positioned on a bottom surface of the transparent base, wherein the wafer carrier is attracted by an electrostatic chuck via the conducting layer; and
 - a bonding layer positioned on a top surface of the transparent base for bonding the wafer and the transparent base.
- Claim 13 (original) The wafer carrier of claim 12, wherein the transparent base has dimensions similar to that of the wafer.
 - Claim 14 (original) The wafer carrier of claim 12, wherein the transparent base is a glass wafer.
- 25 Claim 15 (original) The wafer carrier of claim 12, wherein the transparent base is a quartz wafer.
- Claim 16 (original) The wafer carrier of claim 12, wherein the bonding layer is selected from the group consisting of double-sided tape, ultra violet tape, thermal sensitive tape, photo resist, and wax.
 - Claim 17 (previously presented) The wafer carrier of claim 12, wherein-the wafer is

transferred and undergoes the double-sided process.

Claim 18 (original) The wafer carrier of claim 17, wherein the wafer comprises at least an alignment mark.

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Claim 19 (original) The wafer carrier of claim 18, wherein the conducting layer is a transparent conducting layer.

Claim 20 (original) The wafer carrier of claim 18, wherein the conducting layer is a non-transparent conducting layer having at least an exposed region corresponding to the alignment mark.

Claim 21 (original) The wafer carrier of claim 12, wherein the non-transparent conducting layer comprises a plurality of conducting patterns connected with each other.